#14/Q 11-20-02 D.BE!!

NOV 1 3 2002 2

PATENT

DKT. NO.: 29273/502

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

PLICANTS

Hajime KAWANO, et al.

SERIAL NO.

09/315,988

FILED

May 21, 1999

FOR

ELECTRON BEAM LITHOGRAPHY SYSTEM

GROUP ART

2881

EXAMINER

Kalimah Fernandez

Assistant Commissioner for Patents Washington D.C. 20231

AMENDMENT

Sir:

In response to the office action dated May 22, 2002, the due date being extended by the attached Petition for Extension of Time, please amend the above-identified application as follows:

IN THE CLAIMS

Please amend claim 1 as follows:

1. (Amended) An electron beam lithograph system comprising:

exposure map creating means which, based on positional relations between meshes dividing a region to be rendered by an electron beam on the one hand and shots to be rendered by said electron beam on the other hand, creates an exposure map by calculating an area density from a shot area included in each of said meshes; and

proximity affect correcting means for correcting a level of exposure for each of said shots by referencing said exposure map so that each shot is exposed at the corrected level;

wherein said exposure map creating means includes judging means for judging whether or not each shot straddles a plurality of meshes by using a plurality of memories and adding circuits.

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